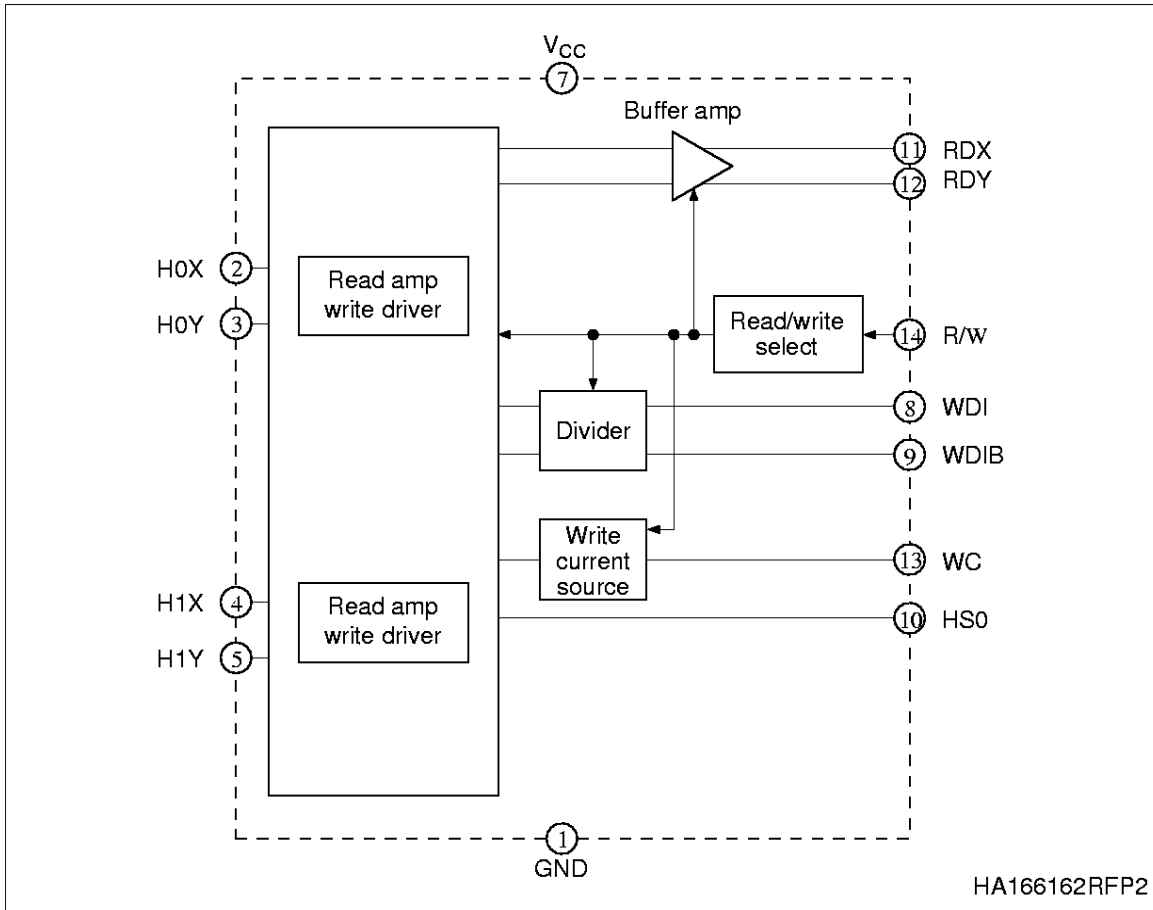


HA166162RFP2, HA166163RFP4

Pin Description

Pin No.				Symbol	Pin Name	Description
HA166162	HA166163					
1	1	GND	Ground			Ground pins
2, 3	2, 3	H0X, H0Y	Head 0X, 0Y			These pins are connected to the R/W head coil of channel 0.
4, 5	4, 5	H1X, H1Y	Head 1X, 1Y			These pins are connected to the R/W head coil of channel 1.
6	11	NC				
7	10	V _{CC}	5 V			5 V power supply
8, 9	12, 13	WDI, WDIB	Write data input			Write data input pin. The positive edge of WDI toggles head current.
10	15	HS0	Head select 0			Input pins for head select signals. Refer to the head select table.
11, 12	16, 17	RDX, RDY	Read amplifier output			Differential output pins for the read amp. The signal read out from the head coil is amplified and provided on these pins.
13	18	WC	Write current setting			Write current setting pin. The write current is defined by the equation below by connecting the external resistance R _{WC} between this pin and GND. Write current [mA] = K/R _{WC} [kΩ]
14	19	R/W	R/W switch			Mode select switch for changing over the bias condition of the head coil. A low level selects the write mode, while a high level selects the read mode.
	6, 7	H2X, H2Y	Head 2X, 2Y			These pins are connected to the R/W head coil of channel 2.
	8, 9	H3X, H3Y	Head 3X, 3Y			These pins are connected to the R/W head coil of channel 3.
	14	HS1	Head select 1			Input pins for head select signals. Refer to the head select table.
	20	NC				

Block Diagram



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rating	Unit	Applicable Terminal
Supply voltage	V _{CC}	-0.3 to +6.0	V	V _{CC}
Write current	I _W	35	mA	
Interface input voltage	V _{IN}	-0.3 to V _{CC} +0.3	V	HS0 WDI, WDIB, R/w
Read data output current	I _{RO}	-10	mA	RDX, RDY
Operating temperature	T _{opr}	0 to +70	°C	
Storage temperature	T _{stg}	-55 to +150	°C	
Head voltage swing	V _{HSW}	4.0	V _{pp}	
Power dissipation	P _T	550	mW	

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Power Supply (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply voltage range	V _{CC}	4.5	—	5.5	V	
+5.5 V supply current	I _{CC}	—	33	45	mA	Read mode
		—	35 + I _W	43 + I _W		Write mode
		—	6	10	mA	Off mode I _{WC} < 0.15 mA

Electrical Characteristics (V_{CC} = 5 V, Ta = 25°C unless otherwise specified)

Digital Input

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Low level input voltage1	V _{IL1}	-0.3	—	0.8	V	
Low level input current1	I _{IL1}	-100	—	—	μA	V _{IL} = 0.4 V
High level input voltage1	V _{IH1}	2.0	—	V _{CC} + 0.3	V	
High level input current1	I _{IH1}	—	—	20	μA	V _{IH} = 2.0 V
Low level input voltage2	V _{IL2}	V _{CC} - 2	—	V _{CC} - 1.65	V	(WDI, WDIB)
Low level input current2	I _{IL2}	—	—	0.75	mA	V _{IL} = 3.2 V (WDI, WDIB)
High level input voltage2	V _{IH2}	V _{CC} - 1	—	V _{CC} + 0.3	V	(WDI, WDIB)
High level input current2	I _{IH2}	—	—	0.95	mA	V _{IH} = 4.2 V (WDI, WDIB)
Read/write transition time	t _{RW}	—	—	150	ns	
Write/read transition time	t _{WR}	—	—	500	ns	
Head select switching delay time	t _{HS}	—	—	1000	ns	Read mode

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Head Select Table

HS0	HS1	Head Selected
L	L	0
H	L	1
L	H	2
H	H	3

Mode Select Table

R/W	Mode
L	Write
H	Read
H	Read
H	Read

Read Amplifier

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Differential voltage gain	Avd	249	300	351	V/V	f = 300 kHz
Bandwidth	B _W	50	70	—	MHz	−3 dB
Input noise voltage	V _n	—	(0.5)*1	(0.6)*1	nV/√Hz	f ≤ 15 MHz, Inputs shorted
Common mode rejection ratio	CMRR	60	80	—	dB	
Power supply stability	PSRR	45	60	—		V _{CC} ±100 mVp-p, f = 5 MHz
Channel separation	Sep	60	80	—		V _{in} = 100 mVp-p on unselected channels and V _{in} = 0 mVp-p on selected channels, f = 5 MHz
Output offset voltage	V _o	−300	—	300	mV	Inputs shorted
Differential input impedance	R _{in}	—	0.72	—	kΩ	f = 300 kHz f = 5 MHz
Common mode output voltage	V _{com}	2.0	2.5	3.0	V	
Output source current	I _{OSO}	—	−10	—	mA	
Output sink current	I _{OSI}	1.5	2.0	—		
Input capacitance	C _{IN}	—	(10)*1	(15)*1	pF	

Note: 1. These values are only for design purpose.

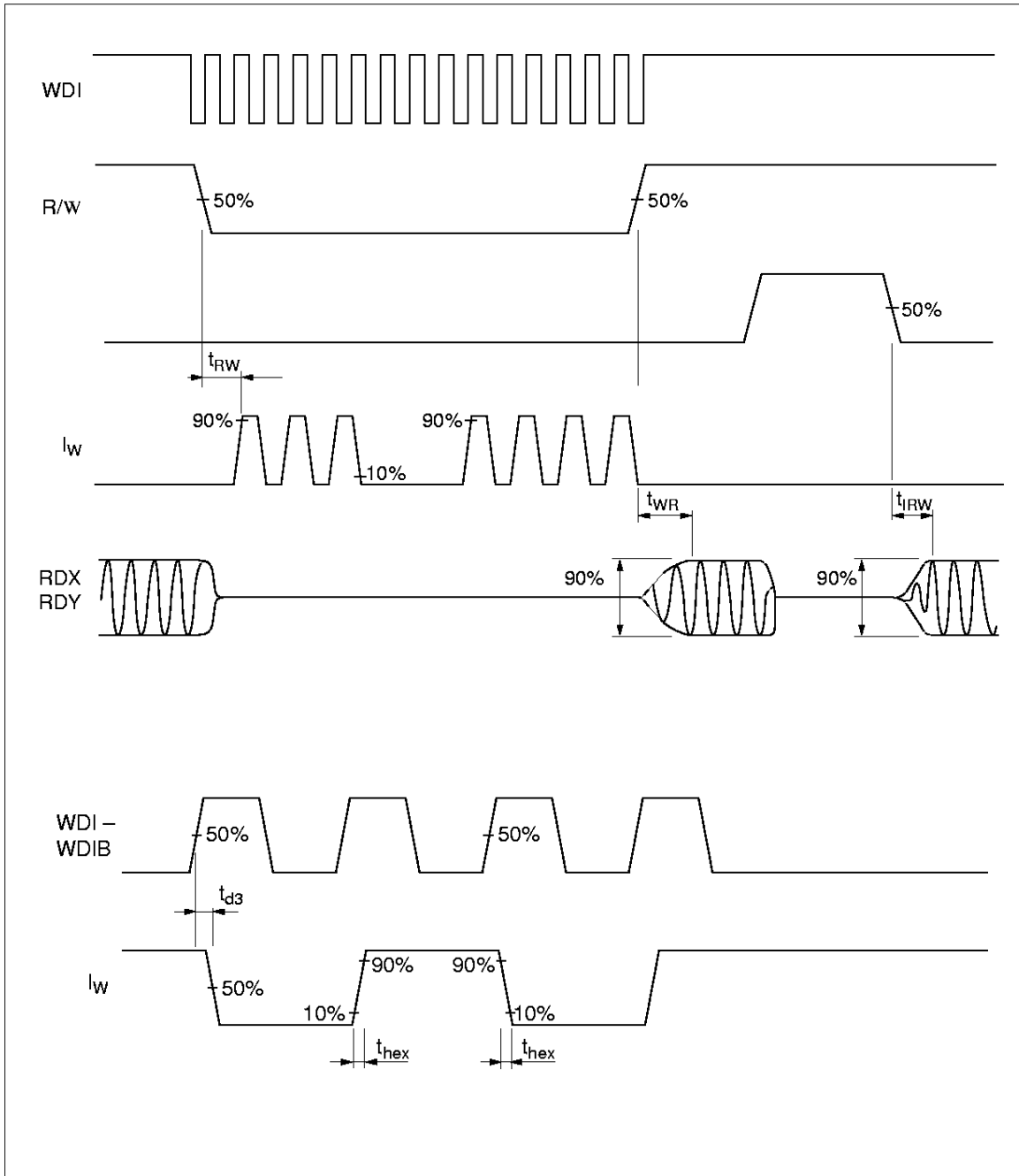
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Write Driver

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Write current setting range	I_W	8	—	20	mA	
Head current rise time	t_{hex}	—	4	15	ns	$L_h = 0 \mu H$, $R_h = 0 \Omega$, 10% to 90% point
Head current switching delay time	t_{d3}	—	—	30		$R_h = 0 \Omega$, $L_h = 0 \mu H$, from 50% point
Head current switching symmetry	t_{d4}	—	—	(1)*1		WDI duty cycle = 50%, rise/fall time = 1 ns
Head current gain	I_H/I_{WC}	—	10.4	—	A/A	Head current/ I_{WC}
WC output voltage	V_{WC}	—	3.4	—	V	$I_H = 10 \text{ mA}$
Write current accuracy	I_{H1}	8.4	10	11.6	mA	$R_{WC} = 3.55 \text{ k}\Omega$
V_{CC} monitor operating range (max)	V_{M1}	3.37	3.67	3.97	V	$I_H \leq 0.5 \text{ mA}$
V_{CC} monitor operating range (min)	V_{M2}	—	—	0	V	$I_h \leq 0.5 \text{ mA}$

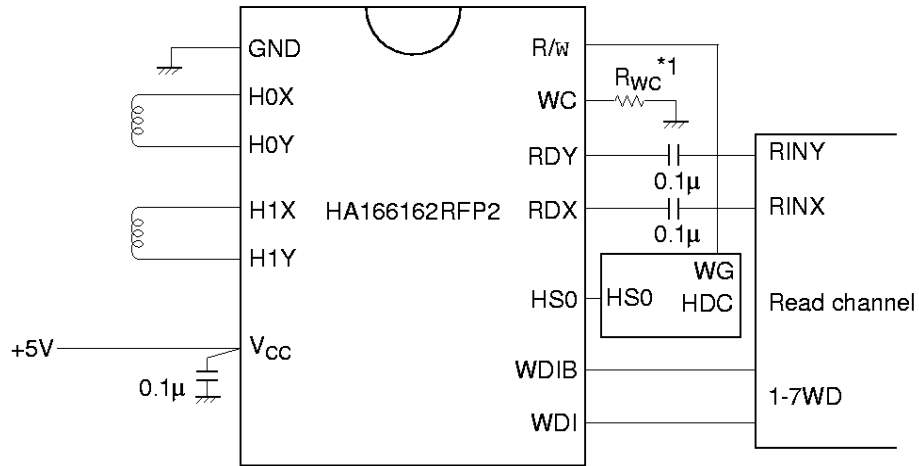
Note: 1. These values are only for design purpose.

Timing Waveforms



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Application Circuit Example



Unit R: Ω
C: F

Notes: 1. External resistance value R_{wc} is determined by following equation.

$$R_{wc} [k\Omega] = \frac{K}{\text{Write current [mA]}}$$

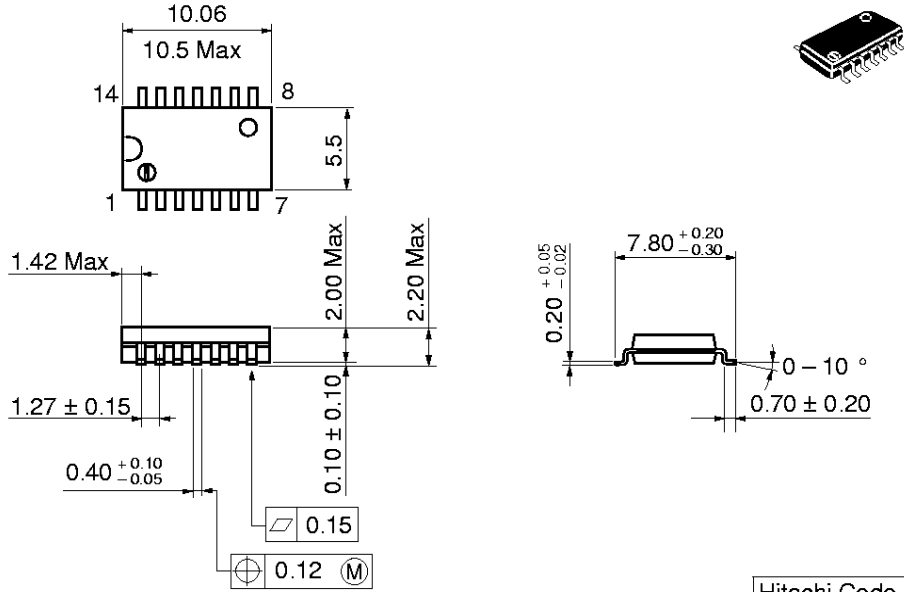
Also, write current ringing on changeover between read and write can be suppressed by locating the resistor R_{wc} as close as possible to the WC pin.

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Package Dimensions

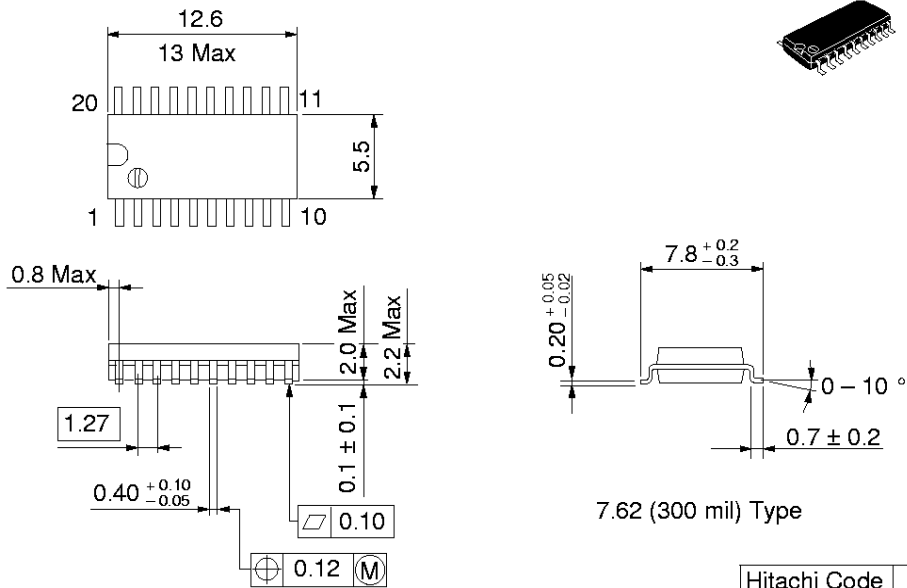
Unit: mm

• HA166162RFP2



Hitachi Code	FP-14DA
EIAJ	SC-529-14B
JEDEC	—

• HA166163RFP4



7.62 (300 mil) Type

Hitachi Code	FP-20DA
EIAJ	SC-531-20
JEDEC	—

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